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Prediction of the electron redundant Si_nN_n fullerenes

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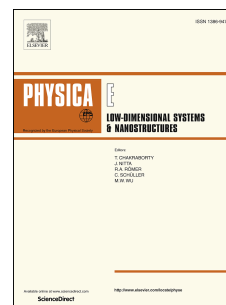
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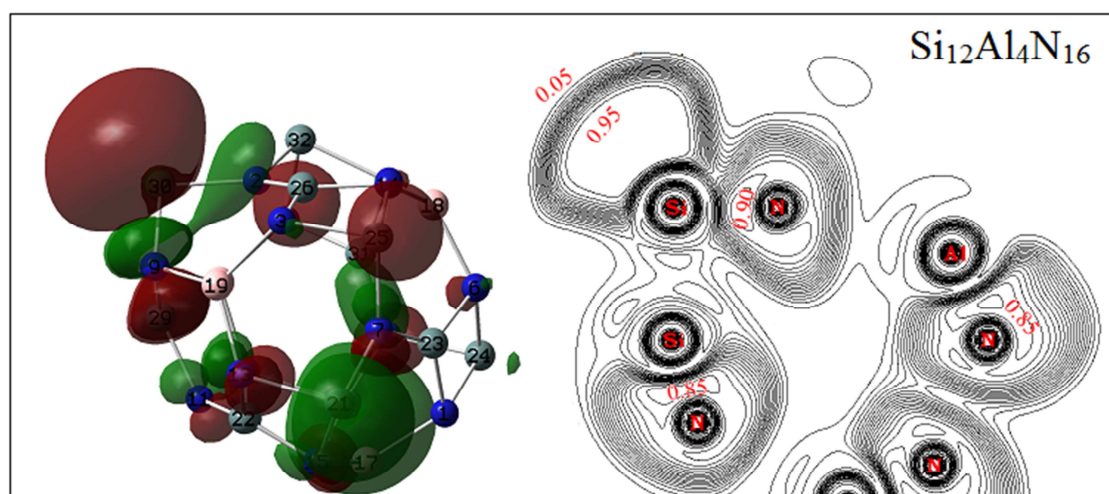
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